

# isc N-Channel MOSFET Transistor

2SK3153

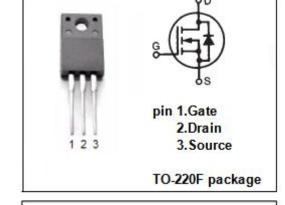
#### **FEATURES**

- Drain Current : I<sub>D</sub>= 15A@ T<sub>C</sub>=25℃
- Drain Source Voltage
  - : V<sub>DSS</sub>=120V(Min)
- · Static Drain-Source On-Resistance
- :  $R_{DS(on)} = 85m \Omega (Max)@ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### **DESCRIPTION**

 motor drive, DC-DC converter, power switch and solenoid drive.

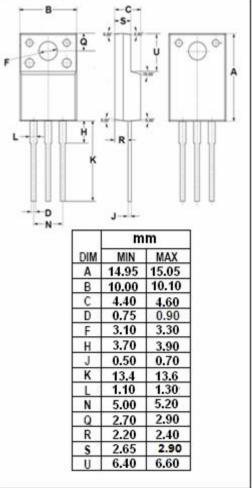


### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	120	V
$V_{GS}$	Gate-Source Voltage-Continuous	±20	V
l <sub>D</sub>	Drain Current-Continuous	15	А
І <sub>DМ</sub>	Drain Current-Single Pluse	60	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	30	W
TJ	Max. Operating Junction Temperature	-55~150	${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~150	${\mathbb C}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	4.17	°C/W



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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	120		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1mA	1	2.5	V
R <sub>DS(on)1</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =8A		85	mΩ
R <sub>DS(on)2</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 4V; I <sub>D</sub> =8A		110	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> = 0		±0.1	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =120V; V <sub>GS</sub> = 0		10	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 15A; V <sub>GS</sub> = 0	-	0.9	V

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